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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



In re Application of:

Dipankar Chandra, et al.

Filing Date:

November 13, 2001

Title:

SENSOR FOR DETECTING SMALL

CONCENTRATIONS OF A TARGET MATTER

Assistant Commissioner
For Patents and Trademarks
Washington, DC 20231

Dear Sir:

INFORMATION DISCLOSURE STATEMENT

Applicants respectfully request, pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, that the references listed on the attached PTO-1449 form be considered and cited in the examination of the above-identified application. Copies of these references are enclosed for the convenience of the Examiner. Furthermore, pursuant to 37 C.F.R. § 1.97(g) and (h), no representation is made that these references are material to patentability of the present application or that a search has been made.

Respectfully submitted,

BAKER BOTTS L.L.P. Attorneys for Applicants

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Date:

11/13/01

Information Disclosure Citation in an Application

Application No.

Applicant(s)
Dipankar (nmi) Chandra, et al.

Docket Number
004578.1148

Applicant(s)
Dipankar (nmi) Chandra, et al.

Filing Date

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a ()		DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
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NON-PATENT DOCUMENTS

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DATE CONSIDERED **EXAMINER**

EXAMINER Initial if citation considered, whether or not citation is an conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

U.S. Patent and Trademark Office